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Anomalous dip observed in intensity autocorrelation function as an inherent nature of single-photon emitters

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We report the observation of an anomalous antibunching dip in intensity autocorrelation function with photon correlation measurements on a single-photon emitter (SPE). We show that the anomalous dip observed is a manifestation of quantum nature of SPEs. Taking population dynamics in a quantum two-level system into account correctly, we redefine intensity autocorrelation function. This is of primary importance for precisely evaluating the lowest-level probability of multiphoton generation in SPEs toward realizing versatile pure SPEs for quantum information and communication. © 2012 American Institute of Physics. [http://dx.doi.org/10.1063/1.4760222]

A variety of single-photon emitters (SPEs)1–21 have been widely investigated for applications in quantum key distribution (QKD),22 quantum information processing,23 and quantum metrology.24 Single-photon emission has been demonstrated by using quantum two-level systems formed in single molecules,1–12 atoms,13–16 ions,17 color centers in diamond,18–20 and semiconductor quantum dots (QDs).10–21 Generating single-photon pure state is crucial for assuring the firm security in the cryptography25 and also minimizing error rate in linear optical quantum computing.26 Therefore, suppression of the multiphoton generation is strongly required for the practical SPEs. Recently, with a variety of quantum systems, SPEs with considerably low multiphoton probability have been reported,1,13,15 and implementation to the prototype QKD systems has also been demonstrated.6,8,14,16

Photons generated from SPEs are generally inspected with the Hanbury-Brown and Twiss (HBT) setup,27 where photons separated into two arms are introduced to single-photon detectors located on each arm for photon correlation measurements. The intensity autocorrelation function28 is composed of coincidence counts as a function of the delay time τ between photon detection events in each detector. The coincidence counts at τ = 0 exhibit a simultaneous photon detection by the two detectors. Therefore, multiphoton generation can be directly measured with coincidence counts at τ = 0 (Refs. 1 and 10–12) and this usually appears as a peak in the intensity autocorrelation function.

In this paper, observation of counterintuitive dip-shaped structure at τ ≈ 0 in intensity autocorrelation function is reported. We show the dip structure originates from an inherent nature of a single quantum emitter. In order to explicitly include population dynamics in a quantum two-level system, we derive an extended form of the conventionally used intensity autocorrelation function. This provides a way to precisely determine the probability of generating single-photon pure states from SPEs over a wide range of operating conditions.

InAs QDs grown on (001) GaAs by metalorganic molecular-beam epitaxy was used to realize a SPE. For isolating a single QD, pillar structures with the diameter of 500 nm were formed with reactive ion etching and were embedded with metal to enhance photon extraction efficiency. Further details on sample preparation are given in Refs. 18 and 19. Optical properties of the QDs were examined by a standard micro-photoluminescence (µ-PL) setup equipped with a mode-locked Ti:sapphire laser (photon energy of 1.3920 eV, pulse repetition period of 13.2 ns, pulse duration of ~5 ps) and a Si charge-coupled-device detector. Figure 1(a) shows a µ-PL spectrum observed from a single QD at 20 K. The excitation power was 2.1 µW which corresponds to the average number of excitons (N_X) photoinjected into the QD of ~0.2. The emission line centered at 1.3214 eV is prominent and we focus on this line hereafter. From the linear excitation power dependence of the PL intensity and the presence of finite exciton fine structure splitting,29 this emission line was assigned to be a neutral exciton (X0).

Under the same excitation condition, a photon correlation measurement was carried out with the HBT setup employing a pair of single-photon counting modules (SPCMs). Resultant intensity autocorrelation function is displayed as black line in Fig. 1(b) with its expanded view around zero delay in the lower trace. The accumulation time for building up the histogram with a multi-channel scaler was about 10 h. Strongly suppressed coincidence counts at τ = 0 manifest highly pure single-photon emission from the present SPE.

Here, we analyze the measured intensity autocorrelation function with a commonly accepted formula under nonresonant pulsed excitation30

\[
N^{-1} \left\{ B + a_0 \exp\left( -\frac{|\tau|}{\tau_e} \right) + \sum_{n \neq 0} a_n \exp\left( -\frac{|\tau - n \cdot T_{rep}|}{\tau_e} \right) \right\},
\]

\[ (1) \]

where a0, an(≠0), Trep, τe, and N are the degree of multiphoton contribution (0 ≤ a0 ≤ 1), correlation peak height of nth excitation cycle (an(≠0) ≡ 1), repetition period of the excitation pulses, decay time constant of the emitter, and the normalization factor, respectively.

Here, B is the baseline originating from an accidental coincidence, estimated to be ~0.009.30 As for τe, we have independently measured the decay profile of the X0 emission

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measured coincidence counts at well reproduced. However, the important finding is that the significant dip at zero assuming an ideal SPE. The overall properties are calculated with Eq. (1) for the ideal SPE. This is a clear indication of the exciton lifetime commonly observed in InAs QDs, with decay times of 0.9 and 6.1 ns. The shorter decay component is the exciton lifetime commonly observed in InAs QDs, while the longer one is most probably due to additional transitions involving other excitonic states, such as dark excitons or charged excitons. Intensity autocorrelation function based on Eq. (1) is simulated and the convoluted result with a system response function. Measured autocorrelation function has a cusp at \( \tau = 0 \), which is not consistent with Eq. (1). The red curve indicates the best fit to the measured function, which gives \( \tau_0 = 0.003 \). Expanded view at \( \tau \sim 0 \) in a logarithmic scale is displayed at the bottom.

![Fig. 1](image1.png)

**Fig. 1.** (a) \( \mu \)-PL spectrum from a single InAs QD. Inset indicates a decay profile of the \( X^0 \) emission line (red circles) and fitted result (black line) convoluted with a response function of our whole system (dotted line). (b) Measured intensity autocorrelation function (black line) for the \( X^0 \) emission line with a time bin of 100 ps. Simulated curves based on Eq. (1) with \( \tau_0 = 0 \) (green dashed line) and Eq. (2) (red line) are also shown. Both curves are convoluted with a system response function. Measured autocorrelation function has a cusp at \( \tau = 0 \), which is not consistent with Eq. (1). The red curve indicates the best fit to the measured function, which gives \( \tau_0 = 0.003 \). Expanded view at \( \tau \sim 0 \) in a logarithmic scale is displayed at the bottom.

line (inset of Fig. 1(a)) and obtained double-exponential decay times of 0.9 and 6.1 ns. The shorter decay component is the exciton lifetime commonly observed in InAs QDs, while the longer one is most probably due to additional transitions involving other excitonic states, such as dark excitons or charged excitons. Intensity autocorrelation function based on Eq. (1) is simulated and the convoluted result with a system response function is displayed as the green dashed line in Fig. 1(b). In this simulation, \( \tau_0 \) was set to zero assuming an ideal SPE. The overall properties are well reproduced. However, the important finding is that the measured coincidence counts at \( \tau \sim 0 \) are lower than the one calculated with Eq. (1) for the ideal SPE. This is a clear indication of the anomalous dip in the intensity autocorrelation function for SPEs, which is essentially alien to the commonly observed one.

The observed dip-shaped coincidence with a cusp at \( \tau = 0 \) reveals that there exists qualitative difference between the measured intensity autocorrelation function and Eq. (1). We discuss, to clarify the difference, the coincidence counts between photons labeled as the first and second photons triggered by the different excitation pulses. Assuming for simplicity that excitation pulse drives the exciton population in a QD, \( p(X_1) \) to unity and the second photons are emitted instantaneously after excitation at \( t = T_{rep} \) (Fig. 2). The \( p(X) \) initiated to unity at \( t = 0 \) will relax to the ground state (GS) with decay time constant of \( \tau_e \) as indicated by the green line in Fig. 2. The coincidence between the first and second photons indicated by the black arrow occurs at the delay time of \( \tau = T_{rep} - \tau_0 \), and its counts are proportional to \( \exp(-t_0/\tau_e) \), which is the exciton population at the time of the first photon emission. Provided that the exciton population at \( t = 0 \) decays independently of the next excitation at \( t = T_{rep} \), the coincidence counts could be recorded even for \( t \geq T_{rep} (\tau \leq 0) \) as shown in the gray arrow. The conventional formula (Eq. (1)) is formulated under this situation, in which all the contribution of the photon pairs to the coincidence counts is summed up uncorrelatedly to the population dynamics which takes place in the excitation and emission processes (green dashed curve in Fig. 1(b)). In a realistic quantum two-level system, in contrast, once the first photon is emitted at the time \( t_0 (0 \leq t_0 \leq T_{rep}) \), the population in a QD is reset to the GS and keeps in the GS until experiencing the next excitation at \( t = T_{rep} \) as displayed by the black dashed arrow in Fig. 2. Therefore, no coincidence count is possible for \( \tau \leq 0 \). This gives rise to the essential difference between observed intensity autocorrelation function and Eq. (1).

![Fig. 2](image2.png)

**Fig. 2.** Schematic of the dynamics of exciton population in a QD. Green thin line indicates the decay profile of exciton populated at \( t = 0 \) as a function of \( t \) (bottom axis) and delay time \( \tau \) with respect to \( t = T_{rep} \) (upper axis). After the first photon emission at \( t_0 \), system stays in the ground state until next excitation (black dashed arrow). Black arrow indicates possible coincidence between the first and second photon emissions, while the gray arrow corresponds to unphysical coincidence in which the exciton decay is independent of the subsequent excitations as reflected in Eq. (1).
\[ \tilde{g}^{(2)}(\tau \geq 0) = N^{-1} \left\{ B + x_0 \exp \left( -|\tau|/\tau_e \right) + \sum_{n=0}^N x_n \exp \left( -|\tau-n \cdot \text{Trep}|/\tau_e \right) \times \left[ 1 - \exp(-|\tau|/\tau_e) \right] \right\} \]

and \[ \tilde{g}^{(2)}(\tau \leq 0) = \tilde{g}^{(2)}(-\tau). \]

In comparison to Eq. (1), the anomalous dip observed at \( \tau \sim 0 \) is satisfactorily reproduced with the \( \tilde{g}^{(2)}(\tau) \) as indicated by the red line in Fig. 1(b). Furthermore, the extended function allows us to precisely determine the multiphoton contribution of \( x_0 = 0.003 \) which cannot be derived with Eq. (1). These results demonstrate that considering the population dynamics, as an inherent nature of quantum emitters, is essential for evaluating the intensity autocorrelation function under the pulsed excitation.

In what follows, we discuss the condition for emerging the anomalous antibunching dip based on Eq. (2). The anomalous dip is caused by applying the modulation term \( 1 - \exp(-|\tau|/\tau_e) \) to unphysical coincidence counts excited by exciton population at \( t = \text{Trep} \), i.e., \( \exp(-|\text{Trep}|/\tau_e) \) (see Fig. 2 and Eq. (1)). Thus, for evaluating the \( x_0 \), it is beneficial to describe the dip depth as a function of \( \text{Trep}/\tau_e \) which is specified by selecting the emitter and the repetition period of the excitation. Here, we introduce the dip depth defined by \( \Delta - \tilde{g}^{(2)}(0) = \Delta - x_0 \), where \( \Delta \) is the lower limit of the coincidence counts at \( \tau = 0 \) without considering the inherent nature of quantum emitter, \( 3^5 \) and we set \( B = 0 \). Figure 3 presents the calculated dip depth as a function of \( \text{Trep}/\tau_e \) for some \( x_0 \) values. In this figure, all traces tend to \(-x_0\) for sufficiently high \( \text{Trep}/\tau_e \), which indicates that peak-shaped coincidence with the amplitude of \( x_0 \) appears as the multiphoton contribution. In this condition, Eq. (2) reduces to Eq. (1). Actually, in most of the reports, \( x_0 \) has been evaluated with relatively high \( \text{Trep}/\tau_e \) region such as \( >10 \). \( 1^5,10,11,14 \) However, for the low \( \text{Trep}/\tau_e \) region, dip-shaped coincidence emerges. This is because the coincidence counts based on the uncorrelated decay (green dashed line in Fig. 2) are overestimated, and the amplitude of modulation required to include the quantum nature is enhanced for the low \( \text{Trep}/\tau_e \). Thus, the conventional formula (Eq. (1)) is no longer valid. In the present case, since \( \text{Trep}/\tau_e \sim 2.2 \) and \( \Delta > x_0 \), the anomalous dip was clearly observed as indicated by Fig. 1(b). Therefore, it is essential to employ the \( \tilde{g}^{(2)}(\tau) \) especially for the SPEs with low \( x_0 \) operating with low \( \text{Trep}/\tau_e \) conditions such as high repetition cycles. \( 20,21 \)

Note that the fine fitting for the height of each correlation peak at \( \tau = n \cdot \text{Trep} \) (\( n \geq 1 \)) shown in Fig. 2 is due to relatively low excitation condition such that \( N_X \sim 0.2 \). For larger excitation power, the peak heights are subject to the effect of excitation rate of \( G \) as is the case with the well-known antibunching lineshape in a single-photon emission under cw excitation. \( 36 \) On the other hand, the derived modulation term \( 1 - \exp(-|\tau|/\tau_e) \) is irrelevant to the \( G \) for \( \tau \sim 0 \) since the system is free from excitation.

In conclusion, we have reported the observation of an anomalous antibunching dip in intensity autocorrelation function with a semiconductor single-photon emitter. By redefining the autocorrelation function to include the population dynamics in quantum emitters, the observed dip was clearly interpreted. Applying the extended autocorrelation function to the result of the photon correlation measurements enables us to evaluate one of the most important figure of merit \( x_0 \) even with relatively low \( \text{Trep}/\tau_e \) condition evoking a dip at around zero delay. Our findings are invaluable to deal with versatile single-photon emitters demanded for the state-of-the-art quantum information devices.

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